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November 2014

# BC546 / BC547 / BC548 / BC549 / BC550 NPN Epitaxial Silicon Transistor

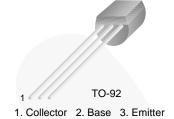
#### **Features**

• Switching and Amplifier

• High-Voltage: BC546, V<sub>CEO</sub> = 65 V

• Low-Noise: BC549, BC550

• Complement to BC556, BC557, BC558, BC559, and BC560



## **Ordering Information**

Part Number	Marking	Package	Packing Method				
BC546ABU	BC546A	TO-92 3L Bulk					
BC546ATA	BC546A	TO-92 3L Amm					
BC546BTA	BC546B	TO-92 3L Am					
BC546BTF	BC546B	TO-92 3L	Tape and Reel				
BC546CTA	BC546C	TO-92 3L	Ammo				
BC547ATA	BC547A	TO-92 3L	Ammo				
BC547B	BC547B	TO-92 3L Bull					
BC547BBU	BC547B	B TO-92 3L Bulk					
BC547BTA	BC547B	.7B TO-92 3L Amn					
BC547BTF	BC547B	TO-92 3L Tape a					
BC547CBU	BC547C	TO-92 3L	Bulk				
BC547CTA	BC547C	TO-92 3L	Ammo				
BC547CTFR	BC547C	TO-92 3L Tape and					
BC548BU	BC548	TO-92 3L Bulk					
BC548BTA	BC548B	TO-92 3L Ammo					
BC548CTA	BC548C	TO-92 3L Ammo					
BC549BTA	BC549B	TO-92 3L Ammo					
BC549BTF	BC549B	TO-92 3L Tape and Ree					
BC549CTA	BC549C	TO-92 3L Ammo					
BC550CBU	BC550C	TO-92 3L	Bulk				
BC550CTA	BC550C	TO-92 3L	Ammo				

1

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Param	Value	Unit		
		BC546	80		
$V_{CBO}$	Collector-Base Voltage	BC547 / BC550	50	V	
		BC548 / BC549	30		
		BC546	65		
$V_{CEO}$	Collector-Emitter Voltage	BC547 / BC550	45	V	
		BC548 / BC549	30		
V	Emitter Page Voltage	BC546 / BC547	6	V	
V <sub>EBO</sub>	Emitter-Base Voltage	BC548 / BC549 / BC550	5	V	
I <sub>C</sub>	Collector Current (DC)		100	mA	
P <sub>C</sub>	Collector Power Dissipation		500	mW	
T <sub>J</sub>	Junction Temperature		150	°C	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C	

### **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol		Parameter	Conditions	Min.	Тур.	Max.	Unit				
I <sub>CBO</sub>	Collector Cut-Off Current		$V_{CB} = 30 \text{ V}, I_{E} = 0$			15	nA				
h <sub>FE</sub>	DC Curre	ent Gain	$V_{CE} = 5 \text{ V}, I_{C} = 2 \text{ mA}$	110		800					
\/ (cat)	Collector	-Emitter Saturation	$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		90	250	m\/				
V <sub>CE</sub> (sat)	Voltage		I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5 mA		250	600	mV				
\/ (cat)	Baca Em	eittor Saturation Valtage	$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		700		m\/				
V <sub>BE</sub> (sat)	Dase-Ell	nitter Saturation Voltage	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5 mA	- 4	900		mV				
\/ (on)	) Base-Emitter On Voltage		V <sub>CE</sub> = 5 V, I <sub>C</sub> = 2 mA	580	580 660 700						
V <sub>BE</sub> (on) Base-En		iliter On voltage	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA			720	mV				
f <sub>T</sub>	Current Gain Bandwidth Product		$V_{CE} = 5 \text{ V, } I_{C} = 10 \text{ mA,}$ f = 100 MHz		300		MHz				
C <sub>ob</sub>	Output C	apacitance	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz		3.5	6.0	pF				
C <sub>ib</sub>	Input Capacitance		$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		9		pF				
		BC546 / BC547 / BC548	$V_{CE} = 5 \text{ V}, I_{C} = 200 \mu\text{A},$		2.0	10.0					
NF	Noise	BC549 / BC550	$f = 1$ kHz, $R_G = 2$ kΩ		1.2	4.0	dB				
INF	Figure	BC549	$V_{CE} = 5 \text{ V}, I_{C} = 200 \mu\text{A},$		1.4	4.0	uБ				
			$R_G = 2 k\Omega$ , $f = 30 \text{ to } 15000 \text{ MHz}$		1.4	3.0					

## **h**<sub>FE</sub> Classification

Classification	A	В	С			
h <sub>FE</sub>	110 ~ 220	200 ~ 450	420 ~ 800			

## **Typical Performance Characteristics**

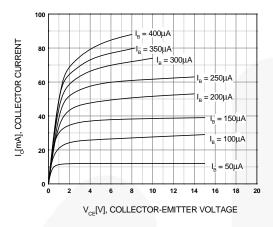


Figure 1. Static Characteristic

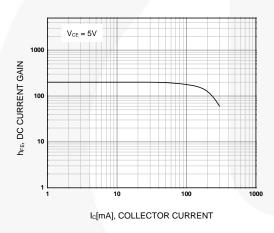


Figure 3. DC Current Gain

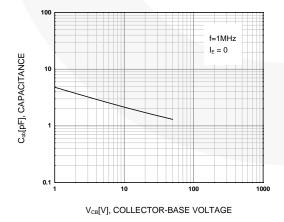


Figure 5. Output Capacitance

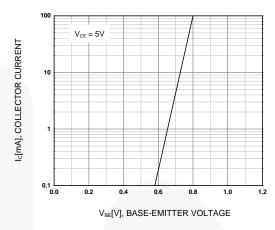


Figure 2. Transfer Characteristic

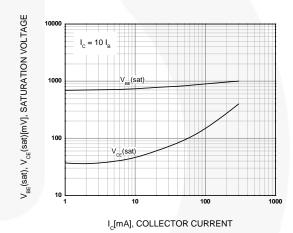


Figure 4. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

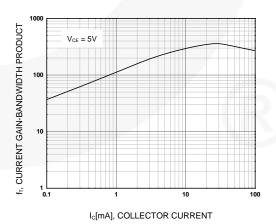
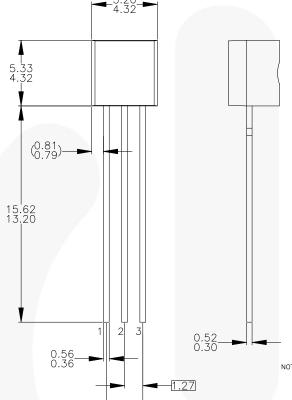


Figure 6. Current Gain Bandwidth Product

## **Physical Dimensions**



2.54

2 3 

\_4.19 3.05

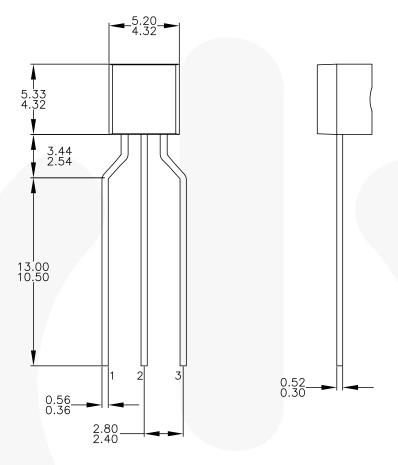
NOTES: UNLESS OTHERWISE SPECIFIED

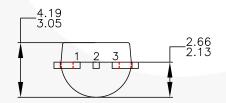
- DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
  ALL DIMENSIONS ARE IN MILLIMETERS.
  DRAWING CONFORMS TO ASME Y14.5M-1994.
  TO-92 (92,94,96,97,98) PIN CONFIGURATION:

	Z Z		92			94			96			97			98		ı
	ā	Ρ	F	М	Ρ	F	М	В	F	М	Ρ	F	М	Ρ	F	М	i
	1	Е	S	S	Ε	S	S	В	D	G	С	G	D	С	G	D	ı
	2	В	D	G	С	G	D	Ε	S	S	В	D	G	Ε	S	S	i
	3	С	G	D	В	D	G	С	G	D	Ε	S	S	В	D	G	i
66 13	LEGEND:   P - BIPOLAR   E - EMITTER   D - DRAIN   F - JFET   B - BASE   S - SOURCE   M - DMOS   C - COLLECTOR   G - GATE																
		E) F)	,	PIN ARE	CO INT	NFIC ERC	GE GUR/ CHAI LEN.	ATIO NGE	N [ AGL	RAI E A	N " T JI	D" FET	AND "F"	SC	UR	CE N.	"S"

Figure 7. 3-Lead, TO-92, JEDEC TO-92 Compliant Straight Lead Configuration, Bulk Type

## Physical Dimensions (Continued)





NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-2009. DRAWING FILENAME: MKT-ZAO3FREV3. FAIRCHILD SEMICONDUCTOR.

Figure 8. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form, Ammo, Tape and Reel Type





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Rev. 172